

Product Specification

40BASE-SR4 100m QSFP+ Gen2 Optical Transceiver Module FTL410QE2C

PRODUCT FEATURES

- Four-channel full-duplex transceiver module
- Hot Pluggable QSFP+ form factor
- Maximum link length of 100m on OM3 Multimode Fiber (MMF) and 150m on OM4 MMF
- Multirate capability: 1.06Gb/s to 10.5Gb/s per channel
- Unretimed XLPI electrical interface
- Maximum power dissipation <1.5W
- Reliable VCSEL array technology
- Built-in digital diagnostic functions
- Commercial operating case temperature range: 0°C to 70°C
- Single 1x12 MPO receptacle
- RoHS-6 Compliant (lead-free)



APPLICATIONS

- 40GBASE-SR4 40G Ethernet
- Breakout to 10GBASE-SR Ethernet
- Proprietary interconnections

Finisar's FTL410QE2C QSFP+ transceiver modules are designed for use in 40 Gigabit per second links over multimode fiber. They are compliant with the QSFP+ MSA^{1,2} and IEEE 802.3ba 40GBASE-SR4³. Digital diagnostics functions are available via an I2C interface, as specified by the QSFP+ MSA. The transceiver is RoHS-6 compliant and lead-free per Directive 2002/95/EC, and Finisar Application Note AN-2038⁵.

PRODUCT SELECTION

FTL410QE2C

I. Pin Descriptions

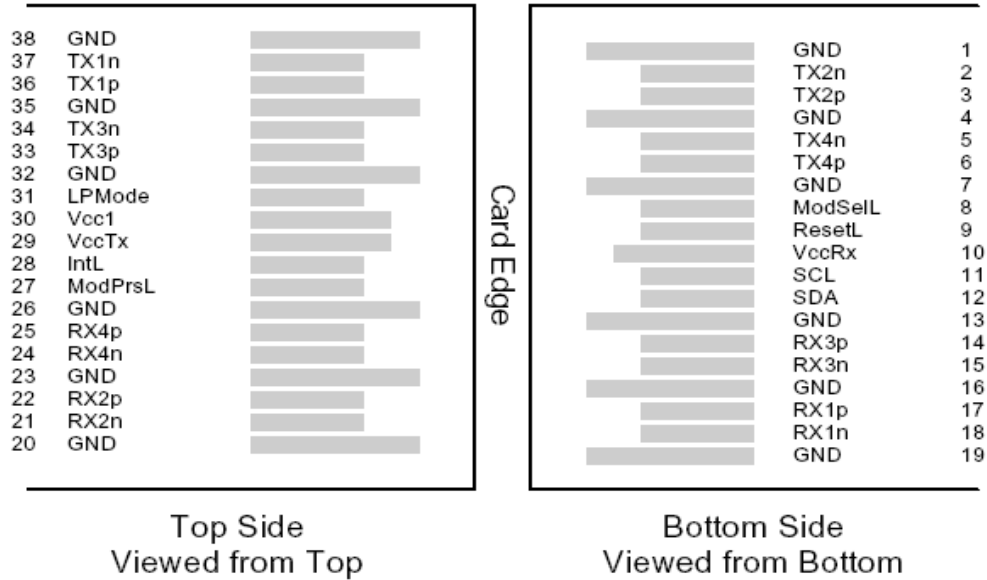


Figure 1 – QSFP+ MSA-compliant 38-pin connector

Pin	Symbol	Name/Description	Notes
1	GND	Ground	1
2	Tx2n	Transmitter Inverted Data Input	
3	Tx2p	Transmitter Non-Inverted Data Input	
4	GND	Ground	1
5	Tx4n	Transmitter Inverted Data Input	
6	Tx4p	Transmitter Non-Inverted Data Input	
7	GND	Ground	1
8	ModSelL	Module Select	
9	ResetL	Module Reset	
10	Vcc Rx	+3.3 V Power supply receiver	
11	SCL	2-wire serial interface clock	
12	SDA	2-wire serial interface data	
13	GND	Ground	1
14	Rx3p	Receiver Non-Inverted Data Output	
15	Rx3n	Receiver Inverted Data Output	
16	GND	Ground	1
17	Rx1p	Receiver Non-Inverted Data Output	
18	Rx1n	Receiver Inverted Data Output	
19	GND	Ground	1
20	GND	Ground	1
21	Rx2n	Receiver Inverted Data Output	
22	Rx2p	Receiver Non-Inverted Data Output	
23	GND	Ground	1
24	Rx4n	Receiver Inverted Data Output	

25	Rx4p	Receiver Non-Inverted Data Output	
26	GND	Ground	1
27	ModPrsL	Module Present	
28	IntL	Interrupt	
29	Vcc Tx	+3.3 V Power supply transmitter	
30	Vcc1	+3.3 V Power Supply	
31	LPMode	Low Power Mode	
32	GND	Ground	1
33	Tx3p	Transmitter Non-Inverted Data Input	
34	Tx3n	Transmitter Inverted Data Input	
35	GND	Ground	1
36	Tx1p	Transmitter Non-Inverted Data Input	
37	Tx1n	Transmitter Inverted Data Input	
38	GND	Ground	1

Notes

1. Circuit ground is internally isolated from chassis ground.

II. General Product Characteristics

Parameter	Value	Unit	Notes
Module Form Factor	QSFP+		
Number of Lanes	4 Tx and 4 Rx		
Maximum Aggregate Data Rate	42.0	Gb/s	
Maximum Data Rate per Lane	10.5	Gb/s	Higher bit rates may be supported. Please contact Finisar.
Protocols Supported	Typical applications include 40G Ethernet, Infiniband, Fibre Channel, SATA/SAS3		
Electrical Interface and Pin-out	38-pin edge connector		Pin-out as defined by the QSFP+ MSA
Maximum Power Consumption per End	1.5	Watts	Varies with output voltage swing and pre-emphasis settings (see Figure 2)
Management Interface	Serial, I2C-based, 400 kHz maximum frequency		As defined by the QSFP+ MSA

Data Rate Specifications	Symbol	Min	Typ	Max	Units	Ref.
Bit Rate per Lane	BR	1062		10500	Mb/sec	1
Bit Error Ratio	BER			10^{-12}		2
Link distance on OM3 MMF	d			100	meters	3
Link distance on OM4 MMF	d			150	meters	3

Notes:

1. Compliant with 40G Ethernet. Compatible with 1/10 Gigabit Ethernet and 1/2/4/8/10G Fibre Channel.
2. Tested with a PRBS $2^{31}-1$ test pattern.
3. Per 40GBASE-SR4, IEEE 802.3ba

III. Absolute Maximum Ratings

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Maximum Supply Voltage	V _{cc1} , V _{ccTx} , V _{ccRx}	-0.5		3.6	V	
Storage Temperature	T _S	-40		85	°C	
Case Operating Temperature	T _{OP}	0		70	°C	
Relative Humidity	RH	0		85	%	1
Damage Threshold, per Lane	DT	3.4			dBm	

Notes:

1. Non-condensing.

IV. Electrical Characteristics (T_{OP} = 0 to 70°C, V_{CC} = 3.15 to 3.45 Volts)

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Supply Voltage	V _{cc1} , V _{ccTx} , V _{ccRx}	3.15		3.45	V	
Supply Current	I _{cc}			350	mA	
Link turn-on time						
Transmit turn-on time				2000	ms	2
Transmitter (per Lane)						
Single ended input voltage tolerance	V _{inT}	-0.3		4.0	V	
Differential data input swing	V _{in,pp}	180		1200	mV _{pp}	3
Differential input threshold			50		mV	
AC common mode input voltage tolerance (RMS)		15			mV	
Differential input return loss		Per IEEE P802.3ba, Section 86A.4.1.1			dB	4
J2 Jitter Tolerance	J _{t2}	0.17			UI	
J9 Jitter Tolerance	J _{t9}	0.29			UI	
Data Dependent Pulse Width Shrinkage	DDPWS	0.07			UI	
Eye mask coordinates {X1, X2 Y1, Y2}		0.11, 0.31 95, 350			UI mV	5
Receiver (per Lane)						
Single-ended output voltage		-0.3		4.0	V	
Differential data output swing	V _{out,pp}	0		800	mV _{pp}	7,8
AC common mode output voltage (RMS)				7.5	mV	
Termination mismatch at 1 MHz				5	%	
Differential output return loss		Per IEEE P802.3ba, Section 86A.4.2.1			dB	4
Common mode output return loss		Per IEEE P802.3ba, Section 86A.4.2.2			dB	4
Output transition time, 20% to 80%		28			ps	
J2 Jitter output	J _{o2}			0.42	UI	
J9 Jitter output	J _{o9}			0.65	UI	
Eye mask coordinates #1 {X1, X2 Y1, Y2}		0.29, 0.5 150, 425			UI mV	6

Eye mask coordinates #2 {X1, X2 Y1, Y2}		0.29, 0.5 125, 500	UI mV	5
Power Supply Ripple Tolerance	PSR	50	mVpp	

Notes:

1. Maximum total power value is specified across the full temperature and voltage range.
2. From power-on and end of any fault conditions.
3. After internal AC coupling. Self-biasing 100Ω differential input.
4. 10 MHz to 11.1 GHz range
5. Hit ratio = $5 \times 10E-5$. Valid for all settings in Figure 2.
6. Hit ratio = $5 \times 10E-5$. Valid only for the shaded settings in Figure 2.
7. AC coupled with 100Ω differential output impedance.
8. Settable in 4 discrete steps via the I2C interface. See Figure 2 for Vout settings.

Power (mW)		Pre-Emphasis into 100ohms (mV)			
		0	125	175	325
Vout (mV)	0	599			
	317	751	935	971	1075
	422	787	971	1007	1111
	739	883	1055	1103	1190

Figure 2 – Power Dissipation (mW, maximum) vs. Rx Output Conditions

V. Optical Characteristics ($T_{OP} = 0$ to $70^{\circ}C$, $V_{CC} = 3.15$ to 3.45 Volts)

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Transmitter (per Lane)						
Signaling Speed per Lane			10.5		GBd	1
Center wavelength		840		860	nm	
RMS Spectral Width	SW			0.65	nm	
Average Launch Power per Lane	TXP _x	-7.6		-1.0	dBm	
Transmit OMA per Lane	TxOMA	-5.6		3.0	dBm	2
Difference in Power between any two lanes [OMA]	DP _x			4.0	dB	
Peak Power per Lane	PP _x			4.0	dBm	
Launch Power [OMA] minus TDP per Lane	P-TDP	-6.5			dBm	
TDP per Lane	TDP			3.5	dBm	
Optical Extinction Ratio	ER	3.0			dB	
Optical Return Loss Tolerance	ORL			12	dB	
Encircled Flux	FLX	> 86% at 19 um < 30% at 4.5 um			dBm	
Average launch power of OFF transmitter, per lane				-30	dBm	
Relative Intensity Noise	RIN			-128	dB/Hz	
Transmitter eye mask definition {X1, X2, X3, Y1, Y2, Y3}		0.23, 0.34, 0.43, 0.27, 0.35, 0.4				

Parameter	Symbol	Min	Typ	Max	Unit	Ref.
Receiver (per Lane)						
Signaling Speed per Lane			10.5		GBd	3
Center wavelength		840		860	nm	
Damage Threshold	DT	3.4			dBm	
Average Receive Power per Lane	RXP _x	-9.5		2.4	dBm	
Receive Power (OMA) per Lane	RxOMA			3.0	dBm	
Stressed Receiver Sensitivity (OMA) per Lane	SRS			-5.4	dBm	
Peak Power, per lane	PP _x			4	dBm	
Receiver Reflectance	Rfl			-12	dB	
Vertical eye closure penalty, per lane				1.9	dB	
Stressed eye J2 jitter, per Lane				0.3	UI	
Stressed eye J9 jitter, per Lane				0.47	UI	
OMA of each aggressor lane				-0.4	dBm	
Rx jitter tolerance: Jitter frequency and p-p amplitude		(75, 5)			kHz, UI	
		(375, 1)			kHz, UI	
LOS De-Assert	LOS _D			-12	dBm	
LOS Assert	LOS _A	-30			dBm	
LOS Hysteresis		0.5			dBm	

Notes:

1. Transmitter consists of 4 lasers operating at a maximum rate of 10.5Gb/s each.
2. Even if TDP is <0.9dB, the OMA min must exceed this value.
3. Receiver consists of 4 photodetectors operating at a maximum rate of 10.5Gb/s each.

VI. Memory Map and Control Registers

Compatible with SFF-8436 (QSFP+). Please see Finisar Application Note.

VII. Environmental Specifications

Finisar FTL410QE2C transceivers have an operating temperature range from 0°C to +70°C case temperature.

Environmental Specifications	Symbol	Min	Typ	Max	Units	Ref.
Case Operating Temperature	T _{op}	0		70	°C	
Storage Temperature	T _{sto}	-40		85	°C	

VIII. Regulatory Compliance

Finisar FTL410QE2C transceivers are RoHS-6 Compliant. Copies of certificates are available at Finisar Corporation upon request.

FTL410QE2C transceiver modules are Class 1 laser eye safety compliant per IEC 60825-1.

IX. Mechanical Specifications

The FTL410QE2C mechanical specifications are compliant to the QSFP+ MSA transceiver module specifications.

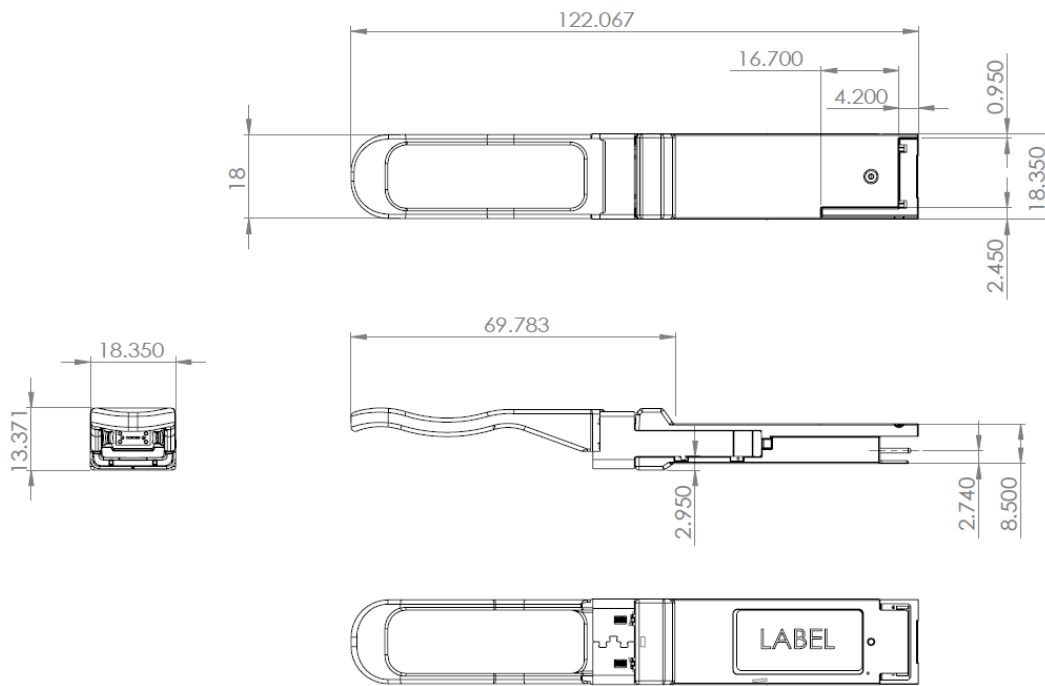


Figure 3 – FTL410QE2C mechanical drawing

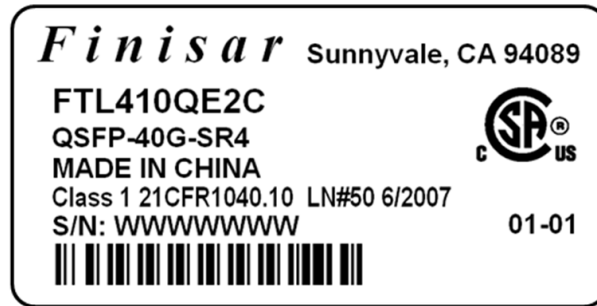


Figure 4 – FTL410QE2C product label

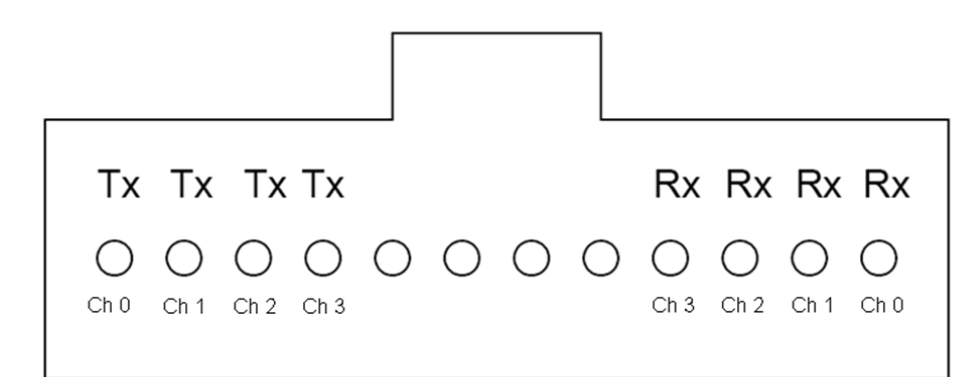


Figure 5 – FTL410QE2C optical lane assignment
(front view of MPO receptacle)

X. References

1. INF-8438i – Specification for QSFP (Quad Small Formfactor Pluggable) Transceiver, Rev 1.0, November 2006
2. SFF-8436 – Specification for QSFP+ Copper and Optical Transceiver, Rev 4.1, August 2011
3. IEEE 802.3ba – PMD Type 40GBASE-SR4.
4. Directive 2002/95/EC of the European Council Parliament and of the Council, “on the restriction of the use of certain hazardous substances in electrical and electronic equipment”. January 27, 2003.
5. “Application Note AN-2038: Finisar Implementation of RoHS Compliant Transceivers”, Finisar Corporation, January 21, 2005.

XI. For More Information

Finisar Corporation
1389 Moffett Park Drive
Sunnyvale, CA 94089-1133
Tel. 1-408-548-1000
Fax 1-408-541-6138
sales@finisar.com
www.finisar.com

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9